Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	1699	protrudent	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/12 18:15
S2	637	third adj ((mask or masking) adj layer)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/12 18:15
S3	2	S2 and S1	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/19 11:14
S4	0	438/39.ccls. and protrudent	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 13:34
S5	102	438/39.ccls. and ridge	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 13:35
S11	0	("7083994").URPN.	USPAT	OR	ON	2007/03/13 14:22
S12	5	("5259925" "5284792" "5790737" "6278173" "6289030").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/03/13 14:22
S13	10	("5419804").URPN.	USPAT	OR	ON	2007/03/13 17:52

S14	17	("4053335" "4376657" "4548654" "4622082" "4851358" "5094963" "5162241" "5296411" "5409563" "5416048" "5418184" "5419804" "5445975" "5478762" "5587325" "5795809" "6004868").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/03/13 17:52
S15	2044	epitaxial adj structure	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 17:55
S16	12	S15 and 438/39.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 17:57
S17	4	438/40.ccls. and (ridge and S15)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 17:58
S18	207	438/43.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 17:58
S19	, 8	("5020067" "5208183" "5256580" "5637511" "5696784" "5717707" "5786234" "5832019").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2007/03/13 18:06
S20	4	("6165811").URPN.	USPAT	OR	ON	2007/03/13 18:36
S21	6	protrudent and ((mask or masking) adj layer)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 18:46

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S22	10	protrudent and (laser adj device)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 18:47
S23	162	438/673.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 18:52
S24	7	S23 and ridge	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 18:53
S25	541	438/734.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 18:55
S26	7	438/734.ccls. and ridge	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 18:54
S27	13	S25 and mesa	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 18:57
S28	7	438/736.ccls. and (ridge or mesa)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/13 18:58

S29	24	438/738.ccls. and (ridge or mesa)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT;	OR	ON	2007/03/13 19:01
S30	199	438/737.ccls.	IBM_TDB US-PGPUB; USPAT;	OR	ON	2007/03/13 19:01
			USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB			
S31	0	("2007/0026685").URPN.	USPAT	OR	ON	2007/03/14 10:54
S32	33353	semiconductor adj laser	USPAT	OR	ON	2007/03/14 10:54
S33	4129	S32 and (ridge or mesa)	USPAT	OR	ON	2007/03/14 10:54
S34	87	S33 and (epitaxial adj structure)	USPAT	OR	ON	2007/03/14 10:55
S38	0	("2004/0248334").URPN.	USPAT	OR	ON	2007/03/16 18:00
S39	300	438/39.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/19 11:23
S40	163	S39 and (semiconductor adj laser)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/19 11:41
S41	121650	(semiconductor adj laser)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/19 11:41
S42	162992	(P adj type) and (N adj type)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/19 13:23

S43	2452	(laser and electrode) with ((n adj type) and (p adj type))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/19 13:24
S44	1579	(N adj type) near (ohmic adj contact)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR ·	ON	2007/03/19 13:24
S45	129	S44 and S43	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/19 13:27
S46	2	"5513202".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/19 13:27
S47	8000	VCSEL	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 10:57
S48	634	S47 and (ohmic adj contact)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 10:57
S49	210498	P adj type	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR .	ON	2007/03/20 11:48

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S50	8386	(Ni adj au)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 11:49
S51	380	S49 near5 S50	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 11:49
S52	169749	RIE or (reactive adj ion adj etching)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 16:35
S53	1272000	(argon or Ar)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 16:35
S54	390	S52 near S53	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 16:37
S55	3524914	methane or ch4 or chlorine or cl or helium or He	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 16:39
S56	602	S55 near S52	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 16:49

S57	64	S56 and (semiconductor adj laser)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 17:11
S58	2	"20050218414".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 17:19
S59	2	"20040248334".pn.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2007/03/20 17:19